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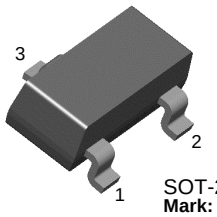
BCW89

PNP General Purpose Amplifier

- This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 300mA.
- Sourced from process 68.



SOT-23
Mark: H3

1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings * T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{CES}	Collector-Emitter Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-5.0	V
I_C	Collector current - Continuous	-500	mA
T_J, T_{stg}	Junction and Storage Temperature	-55 ~ +150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:
1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_C=25°C unless otherwise noted

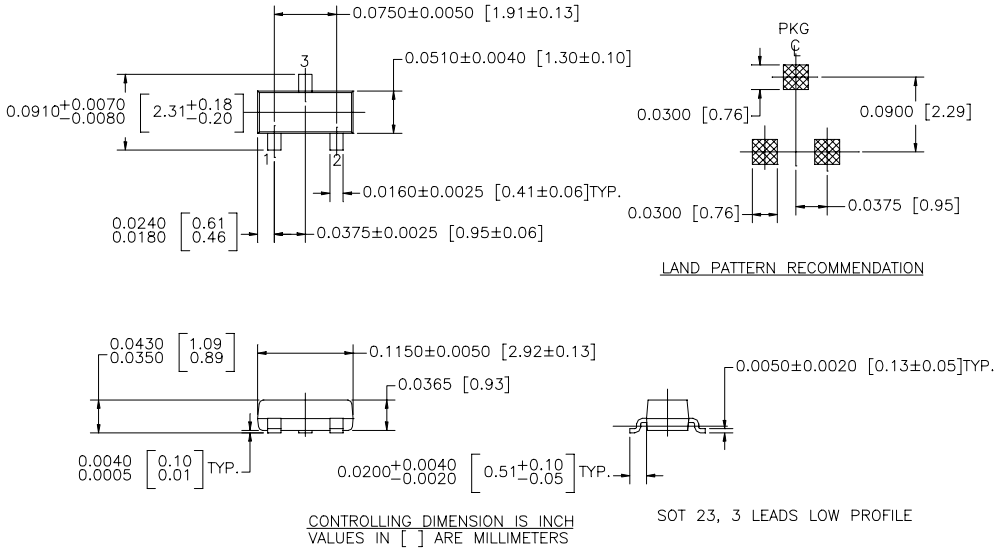
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characteristics					
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = -10μA, I_E = 0	-80		V
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = -2.0mA, I_B = 0	-60		V
$V_{(BR)CES}$	Collector-Emitter Breakdown Voltage	I_C = -10μA, I_E = 0	-60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_C = -10μA, I_C = 0	-5.0		V
I_{CBO}	Collector Cutoff Current	V_{CB} = -20V, I_E = 0 V_{CB} = -20V, I_E = 0, T_A = +100°C		-100 -10	nA μA
On Characteristics					
h_{FE}	DC Current Gain	V_{CE} = -5.0V, I_C = -2.0mA	120	260	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	I_C = -10mA, I_B = -0.5mA		-0.3	V
$V_{BE(on)}$	Base-Emitter On Voltage	V_{CE} = -5.0V, I_C = -2.0mA	-0.6	-0.75	V
Small Signal Characteristics					
NF	Noise Figure	V_{CE} = -5.0V, I_C = -200μA R_S = 2.0kΩ, f = 1.0kHz B_W = 200Hz		10	dB

Thermal Characteristics T_A=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P_D	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Package Dimensions

SOT-23



NOTE : UNLESS OTHERWISE SPECIFIED

1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
2. REFERENCE JEDEC REGISTRATION TO−236, VARIATION AB, ISSUE G, DATED JUL 1993

Dimensions in Millimeters

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